

1S2075(K)

Silicon Epitaxial Planar Diode for High Speed Switching

REJ03G0558-0400

(Previous: ADE-208-144C)

Rev.4.00

Mar 16, 2005

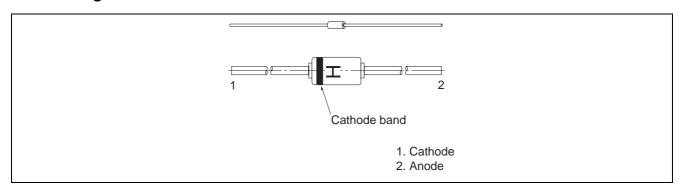
Features

- Low capacitance. (C = 3.5 pF max)
- Short reverse recovery time. $(t_{rr} = 8.0 \text{ ns max})$
- High reliability with glass seal.

Ordering Information

Type No.	Cathode band	Mark	Package Name	Package Code (Previous Code)
1S2075(K)	Green	Н	DO-35	GRZZ0002ZB-A
				(DO-35)

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Peak reverse voltage	V_{RM}	35	V
Reverse voltage	V _R	30	V
Peak forward current	I _{FM}	450	mA
Non-Repetitive peak forward surge current	I _{FSM} *	600	mA
Average rectified current	Io	100	mA
Power dissipation	Pd	250	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	-65 to +175	°C

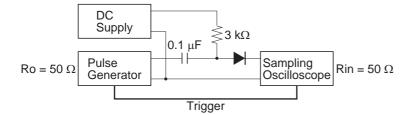
Note: Within 1s forward surge current.

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V_{F}	_	_	0.8	V	I _F = 10 mA
Reverse current	I _R	_	_	100	nA	V _R = 30 V
Capacitance	С	_	_	3.5	pF	V _R = 1 V, f = 1 MHz
Reverse recovery time	t _{rr} *	_	_	8.0	ns	I _F = I _R = 10 mA, Irr = 1 mA

Note: Reverse recovery time test circuit



Main Characteristic

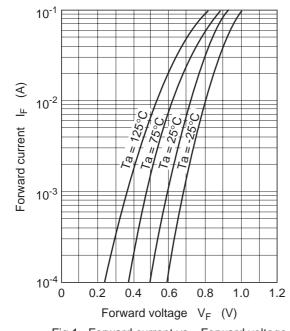


Fig.1 Forward current vs. Forward voltage

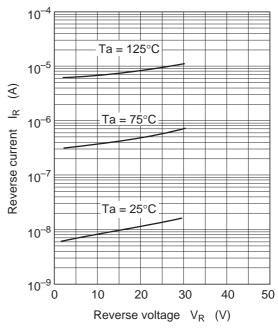
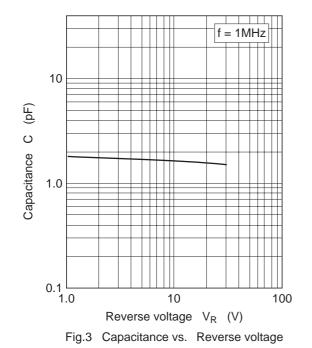
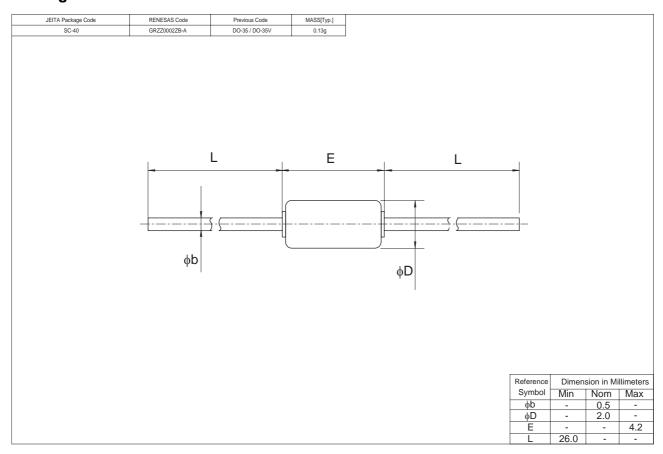


Fig.2 Reverse current vs. Reverse voltage



Package Dimensions



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